**Preferred Device** 

## Power MOSFET 4 Amps, 20 Volts

#### **N-Channel TSOP-6**

These miniature surface mount MOSFETs low  $R_{DS(on)}$  assure minimal power loss and conserve energy, making these devices ideal for use in small power management circuitry. Typical applications are dc-dc converters, power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low R<sub>DS(on)</sub> Provides Higher Efficiency and Extends Battery Life
- Miniature TSOP-6 Surface Mount Package Saves Board Space

#### **MAXIMUM RATINGS** (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	$V_{DSS}$	20	Vdc
Gate-to-Source Voltage - Continuous	V <sub>GS</sub>	± 8.0	Vdc
Drain Current – Continuous @ $T_A = 25^{\circ}C$ – Pulsed Drain Current ( $t_p \le 10 \mu s$ )	I <sub>D</sub>	4.0 20	A
Total Power Dissipation @ $T_A = 25^{\circ}C$ Mounted on FR4 t $\leq$ 5 sec	$P_D$	2.0	W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	– 55 to 150	°C
Thermal Resistance – Junction–to–Ambient	$R_{\theta JA}$	62.5	°C/W
Maximum Lead Temperature for Soldering Purposes, for 10 seconds	TL	260	ŝ

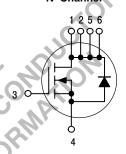


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# 4 AMPERES 20 VOLTS $R_{DS(on)} = 70 \text{ m}\Omega$

#### N-Channel



#### MARKING DIAGRAM

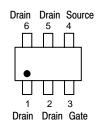


TSOP-6 CASE 318G STYLE 1



442 = Device Code W = Work Week

#### **PIN ASSIGNMENT**



#### ORDERING INFORMATION

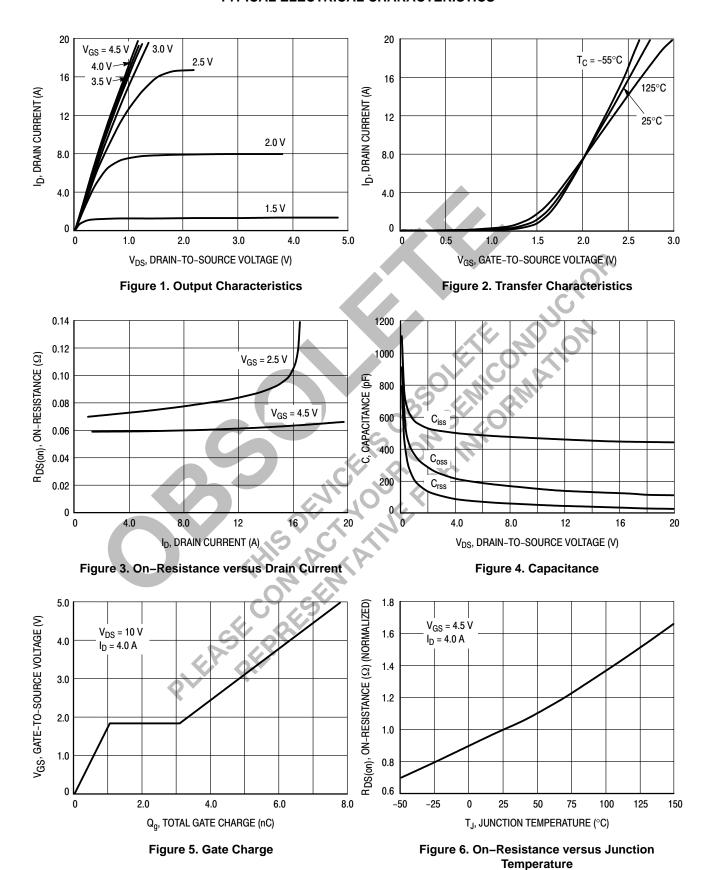
Device	Package	Shipping
MGSF3442VT1	TSOP-6	3000 Tape & Reel

**Preferred** devices are recommended choices for future use and best overall value.

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

	Symbol	Min	Тур	Max	Unit
FF CHARACTERISTICS					
Drain-to-Source Breakdown Voltage (V <sub>GS</sub> = 0 Vdc, I <sub>D</sub> = 10 μA)	V <sub>(BR)DSS</sub>	20	_	_	Vdc
Zero Gate Voltage Drain Current $(V_{DS} = 20 \text{ Vdc}, V_{GS} = 0 \text{ Vdc})$ $(V_{DS} = 20 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_J = 70^{\circ}\text{C})$	I <sub>DSS</sub>		-	1.0 5.0	μAdc
Gate-Body Leakage Current (V <sub>GS</sub> = ± 8.0 Vdc, V <sub>DS</sub> = 0)	I <sub>GSS</sub>	_	-	±100	nAdc
N CHARACTERISTICS (Note 1.)					
Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = 250 \mu Adc)$	V <sub>GS(th)</sub>	0.6	-	-	Vdc
Static Drain–to–Source On–Resistance $(V_{GS} = 4.5 \text{ Vdc}, I_D = 4.0 \text{ A})$ $(V_{GS} = 2.5 \text{ Vdc}, I_D = 3.4 \text{ A})$	r <sub>DS(on)</sub>		0.058 0.072	0.070 0.095	Ohms
YNAMIC CHARACTERISTICS				0	
Input Capacitance (V <sub>DS</sub> = 5.0 V)	C <sub>iss</sub>	-	90	<b>O</b> -2	pF
Output Capacitance (V <sub>DS</sub> = 5.0 V)	C <sub>oss</sub>	-	50	_	
Transfer Capacitance (V <sub>DG</sub> = 5.0 V)	C <sub>rss</sub>		10	_	
WITCHING CHARACTERISTICS (Note 2.)					
Turn-On Delay Time	t <sub>d(on)</sub>	0	8.0	20	ns
Rise Time $(V_{DD} = 10 \text{ Vdc}, I_D = 1.0 \text{ A},$	t <sub>r</sub>		24	40	
Turn–Off Delay Time $V_{GEN} = 10 \text{ V}, R_L = 10 \Omega$	t <sub>d(off)</sub>	-01	36	60	
Fall Time	tr	ΛO,	10	20	
Gate Charge	Q <sub>T</sub>	_	-	-	nC
DURCE-DRAIN DIODE CHARACTERISTICS					
Continuous Current	Is	_	ı	1.0	Α
Pulsed Current	I <sub>SM</sub>	_	ı	5.0	Α
Forward Voltage (Note 2.)	$V_{SD}$	-	-	1.2	V

#### TYPICAL ELECTRICAL CHARACTERISTICS



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#### TYPICAL ELECTRICAL CHARACTERISTICS

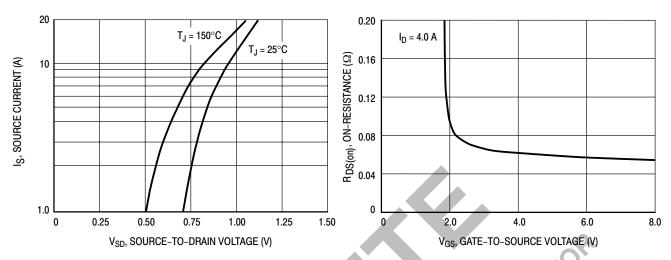


Figure 7. Source-Drain Diode Forward Voltage

Figure 8. On–Resistance versus Gate–to–Source Voltage

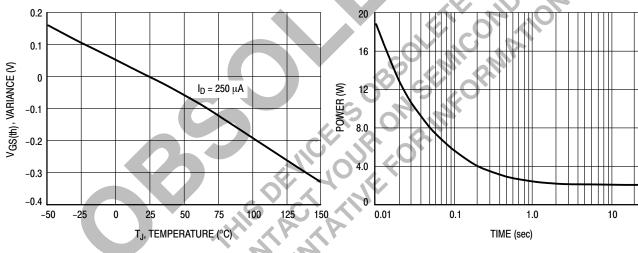


Figure 9. Threshold Voltage

Figure 10. Single Pulse Power

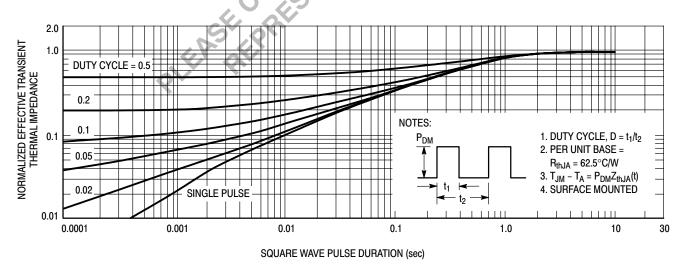


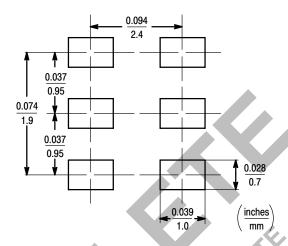
Figure 11. Normalized Thermal Transient Impedance, Junction-to-Ambient

#### INFORMATION FOR USING THE TSOP-6 SURFACE MOUNT PACKAGE

#### MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



#### **TSOP-6 POWER DISSIPATION**

The power dissipation of the TSOP–6 is a function of the drain pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by  $T_{J(max)}$ , the maximum rated junction temperature of the die,  $R_{\theta JA}$ , the thermal resistance from the device junction to ambient, and the operating temperature,  $T_A$ . Using the values provided on the data sheet for the TSOP–6 package,  $P_D$  can be calculated as follows:

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta, JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values

into the equation for an ambient temperature  $T_A$  of 25°C, one can calculate the power dissipation of the device which in this case is 2.0 watts.

$$P_D = \frac{150^{\circ}\text{C} - 25^{\circ}\text{C}}{62.5^{\circ}\text{C/W}} = 2.0 \text{ watts}$$

The 62.5°C/W for the TSOP-6 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 2.0 watts. There are other alternatives to achieving higher power dissipation from the TSOP-6 package. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad ™. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

#### **SOLDERING PRECAUTIONS**

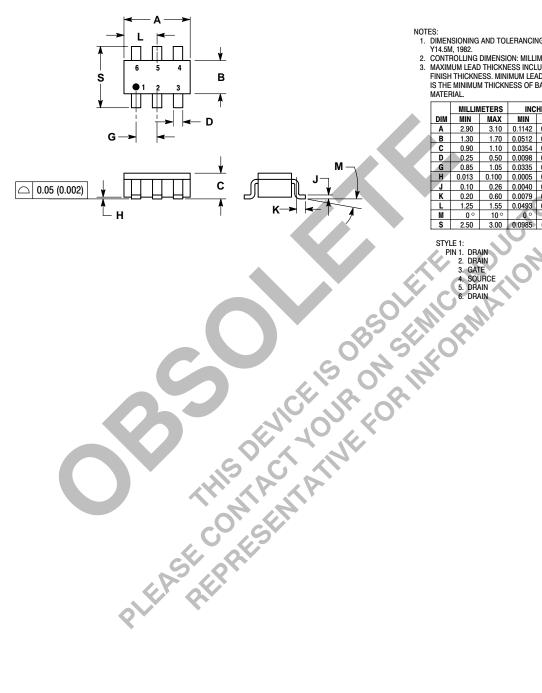
The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.\*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.

- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes.
   Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.
- \* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

#### PACKAGE DIMENSIONS

#### TSOP-6 CASE 318G-02 ISSUE G



#### NOTES:

- NOTES:
  1 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2 CONTROLLING DIMENSION: MILLIMETER.
  3 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	2.90	3.10	0.1142	0.1220	
В	1.30	1.70	0.0512	0.0669	
С	0.90	1.10	0.0354	0.0433	
D	0.25	0.50	0.0098	0.0197	
G	0.85	1.05	0.0335	0.0413	
Н	0.013	0.100	0.0005	0.0040	
7	0.10	0.26	0.0040	0.0102	
K	0.20	0.60	0.0079	0.0236	
L	1.25	1.55	0.0493	0.0610	
M	0 °	10°	0 °	10°	
S	2 50	3.00	0.0985	0 1181	

### **Notes**





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